

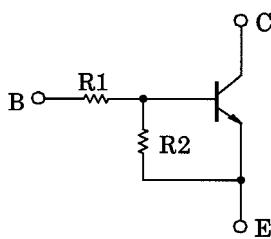
TOSHIBA Transistor Silicon NPN Epitaxial Type (PCT Process)

RN1307,RN1308,RN1309

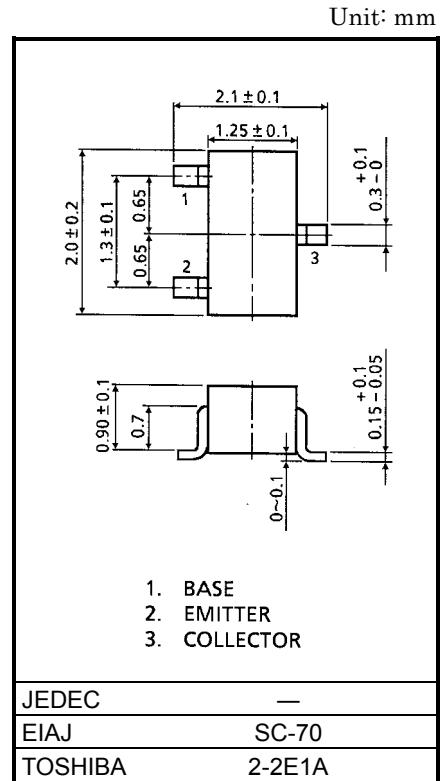
Switching, Inverter Circuit, Interface Circuit
And Driver Circuit Applications

- With built-in bias resistors.
- Simplify circuit design
- Reduce a quantity of parts and manufacturing process
- Complementary to RN2307~RN2309

Equivalent Circuit and Bias Resistor Values



Type No.	R1 (kΩ)	R2 (kΩ)
RN2207	10	47
RN2208	22	47
RN2209	47	22



Maximum Ratings (Ta = 25°C)

Weight: 0.006g

Characteristic		Symbol	Rating	Unit
Collector-base voltage		V _{CBO}	50	V
Collector-emitter voltage		V _{CEO}	50	V
Emitter-base voltage	RN1307	V _{EBO}	6	V
	RN1308		7	
	RN1309		15	
Collector current		I _c	100	mA
Collector power dissipation		P _c	100	mW
Junction temperature		T _j	150	°C
Storage temperature range		T _{stg}	-55~150	°C

Electrical Characteristics ($T_a = 25^\circ\text{C}$)

Characteristic		Symbol	Test Circuit	Test Condition		Min	Typ.	Max	Unit
Collector cut-off current		I_{CBO}	—	$V_{CB} = 50\text{V}$, $I_E = 0$	—	—	100	nA	
		I_{CEO}	—	$V_{CE} = 50\text{V}$, $I_B = 0$	—	—	500		
Emitter cut-off current	RN1307	I_{EBO}	—	$V_{EB} = 6\text{V}$, $I_C = 0$	0.081	—	0.15	mA	
	RN1308		—	$V_{EB} = 7\text{V}$, $I_C = 0$	0.078	—	0.145		
	RN1309		—	$V_{EB} = 15\text{V}$, $I_C = 0$	0.167	—	0.311		
DC current gain	RN1307	h_{FE}	—	$V_{CE} = 5\text{V}$, $I_C = 10\text{mA}$	80	—	—	—	
	RN1308		—		80	—	—		
	RN1309		—		70	—	—		
Collector-emitter saturation voltage		$V_{CE}(\text{sat})$	—	$I_C = 5\text{mA}$, $I_B = 0.25\text{mA}$	—	0.1	0.3	V	
Input voltage (ON)	RN1307	$V_I(\text{ON})$	—	$V_{CE} = 0.2\text{V}$, $I_C = 5\text{mA}$	0.7	—	1.8	V	
	RN1308		—		1.0	—	2.6		
	RN1309		—		2.2	—	5.8		
Input voltage (OFF)	RN1307	$V_I(\text{OFF})$	—	$V_{CE} = 5\text{V}$, $I_C = 0.1\text{mA}$	0.5	—	1.0	V	
	RN1308		—		0.6	—	1.16		
	RN1309		—		1.5	—	2.6		
Translation frequency		f_T	—	$V_{CE} = 10\text{V}$, $I_C = 5\text{mA}$	—	250	—	MHz	
Collector output capacitance		C_{ob}	—	$V_{CB} = 10\text{V}$, $I_E = 0$, $f = 1\text{MHz}$	—	3	6	pF	
Input resistor	RN1307	R1	—	—	7	10	13	kΩ	
	RN1308		—		15.4	22	28.6		
	RN1309		—		32.9	47	61.1		
Resistor ratio	RN1307	R1/R2	—	—	0.191	0.213	0.232	—	
	RN1308		—		0.421	0.468	0.515		
	RN1309		—		1.92	2.14	2.35		

